

# PATENT ASSIGNMENT

Electronic Version v1.1  
 Stylesheet Version v1.1

<b>SUBMISSION TYPE:</b>	NEW ASSIGNMENT												
<b>NATURE OF CONVEYANCE:</b>	ASSIGNMENT												
<b>CONVEYING PARTY DATA</b>													
<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th style="width: 70%;">Name</th> <th style="width: 30%;">Execution Date</th> </tr> </thead> <tbody> <tr> <td>Chau-Wen Wei</td> <td>04/01/2011</td> </tr> <tr> <td>Cheng-Te Chang</td> <td>04/06/2011</td> </tr> <tr> <td>Chin-yuan Huang</td> <td>04/06/2011</td> </tr> <tr> <td>Chih Ming Yang</td> <td>04/01/2011</td> </tr> <tr> <td>Yi-Kan Cheng</td> <td>04/01/2011</td> </tr> </tbody> </table>		Name	Execution Date	Chau-Wen Wei	04/01/2011	Cheng-Te Chang	04/06/2011	Chin-yuan Huang	04/06/2011	Chih Ming Yang	04/01/2011	Yi-Kan Cheng	04/01/2011
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<b>PROPERTY NUMBERS Total: 1</b>													
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<b>CORRESPONDENCE DATA</b>													
<p>Fax Number: (972)732-9218  <i>Correspondence will be sent via US Mail when the fax attempt is unsuccessful.</i></p> <p>Phone: 972-732-1001        Email: errera@slater-matsil.com        Correspondent Name: Slater &amp; Matsil, L.L.P.        Address Line 1: 17950 Preston Road        Address Line 2: Suite 1000        Address Line 4: Dallas, TEXAS 75252</p>													
<b>ATTORNEY DOCKET NUMBER:</b>	TSM10-1174												

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**PATENT**  
**REEL: 026084 FRAME: 0584**

NAME OF SUBMITTER:

Jill M. Errera

Total Attachments: 2

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# ASSIGNMENT

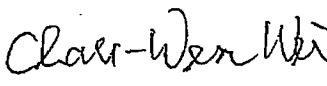
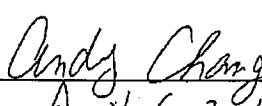
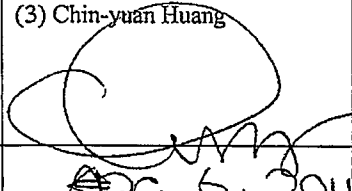
**WHEREAS**, we the undersigned inventors, of residences as listed below, having invented certain new and useful improvements as below entitled, for which application for United States Letters Patent is made, and

**WHEREAS**, Taiwan Semiconductor Manufacturing Company, Ltd., having a principal place of business in Hsin-Chu, Taiwan ("Assignee") desires to acquire our entire right, title and interest in and to the invention, and in and to said application and any Letters Patent that may issue thereon;

**NOW, THEREFORE**, for and in consideration of good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, we assign to Assignee all right, title and interest in and to said invention and in and to said application and all patents which may be granted therefor, and all divisions, reissues, continuations, continuations-in-part and extensions thereof; and in and to any applications filed in any foreign country or group of countries based thereon, including the right to file said foreign applications and to claim priority under the provisions of the International convention and any other relevant convention or treaty; and we hereby authorize and request the Commissioner of Patents and Trademarks to issue all patents for said invention, or patents resulting therefrom, insofar as our interest is concerned, to Assignee.

We also assign to Assignee, all right, title and interest to the invention disclosed in said application throughout the world, including the right to file applications and obtain patents and legal equivalents, including utility models, industrial models and designs for said inventions in its own name throughout the world including all rights to publish cautionary notices reserving ownership of said invention and all rights to register said invention in appropriate registries; and we further agree to execute any and all powers of attorney, applications, assignments, declarations, affidavits, and any other papers in connection therewith necessary to perfect such right, title and interest in Assignee.

We will communicate to Assignee any facts known to us respecting any improvements; and, at the expense of Assignee, we will testify in any legal proceedings, sign all lawful papers, execute all divisional, continuation, continuation-in-part, reissue and substitute applications, make lawful oaths and declarations and generally take all reasonable steps to vest title in Assignee and to aid Assignee to obtain and enforce proper protection for said invention in all countries.

IN WITNESS WHEREOF, I hereunto set hand and seal this day and year;			
TITLE OF INVENTION	Method and Apparatus for Modeling Multi-terminal MOS Device for LVS and PDK		
SIGNATURE OF INVENTOR AND NAME	(1) Chau-Wen Wei 	(2) Cheng-Te Chang 	(3) Chin-yuan Huang 
DATE	April 1st, 2011	April 6, 2011	Apr. 6, 2011
RESIDENCE (CITY AND STATE)	Hsin-Chu, Taiwan	Hsin-Chu, Taiwan	Hsin-Chu, Taiwan

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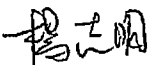
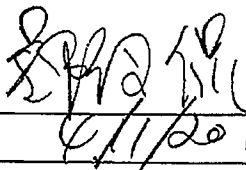
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SIGNATURE OF INVENTOR AND NAME	(4) Chih Ming Yang 	(5) Yi-Kan Cheng 	(6)
DATE	4/7/2011	4/11/2011	
RESIDENCE (CITY AND STATE)	Hsin-Chu, Taiwan	Taipei, Taiwan	

Assignment of Invention

**PATENT**